## NSN 5962-01-339-6328

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-339-6328

Overall Length:
1.290 inches
Overall Height:
0.425 inches
Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/active pull-up and high impedance and 3-state output and bipolar and schottky and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
185.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay time, high to low level output and 100.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

24 printed circuit

**Terminal Type And Quantity:** 

## NSN 5962-01-339-6328

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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